

Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V

Forward Current - 1 A

FEATURES

- ◆Metal silicon junction, majority carrier conduction
- ◆For surface mounted applications
- ◆Low power loss, high efficiency
- ◆High forward surge current capability
- ◆For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆Case: SOD-123FL
- ◆Terminals: Solderable per MIL-STD-750, Method 2026
- ◆Approx. Weight: 15mg / 0.00048oz

Pinning

1.Cathode	2.Anode
	
	
SOD-123FL	

Marking Code

K12	YFW K12	YFW S12
K14	YFW K14	YFW S14
K16	YFW K16	YFW S16
K18	YFW K18	YFW S18
K110	YFW K110	YFW S110
K112	YFW K112	YFW S112
K115	YFW K115	YFW S115
K120	YFW K120	YFW S120

Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 ° ambient temperature unless otherwise specified.Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	K12	K14	K16	K18	K110	K112	K115	K120	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1.0								A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed On Rated Load (JEDEC method)	I_{FSM}	40				30				A
Maximum Instantaneous Forward Voltage at 1 A	V_F	0.55		0.70		0.85		0.90		V
Maximum Instantaneous Reverse Current at Rated DC Reverse Voltage $T_A = 25^{\circ}C$ $T_A = 100^{\circ}C$	I_R	0.3 10				0.2 5		0.1 2		mA
Typical Junction Capacitance ⁽¹⁾	C_j	110		80						pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$	100								°C/W
Operating Junction Temperature Range	T_j	-55 ~ +150								°C
Storage Temperature Range	T_{stg}	-55 ~ +150								°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve

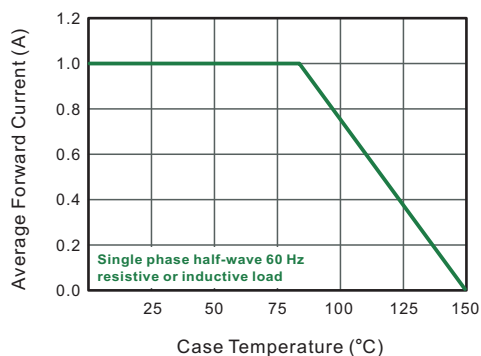


Fig.2 Typical Reverse Characteristics

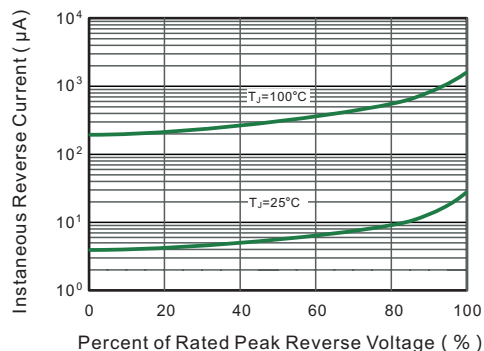


Fig.3 Typical Forward Characteristic

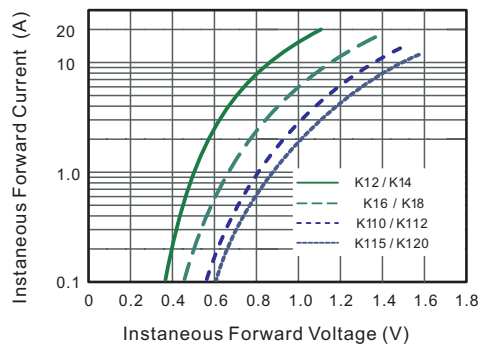


Fig.4 Typical Junction Capacitance

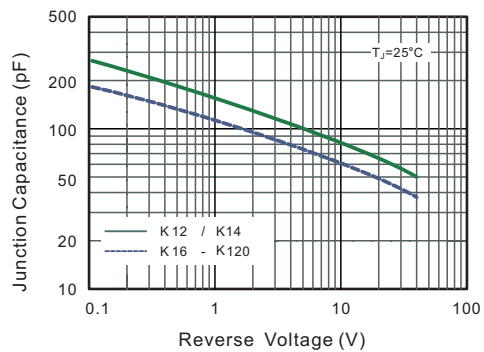


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

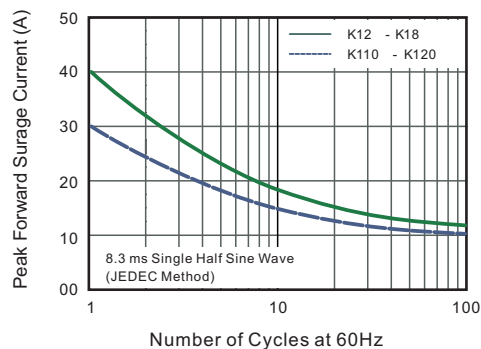
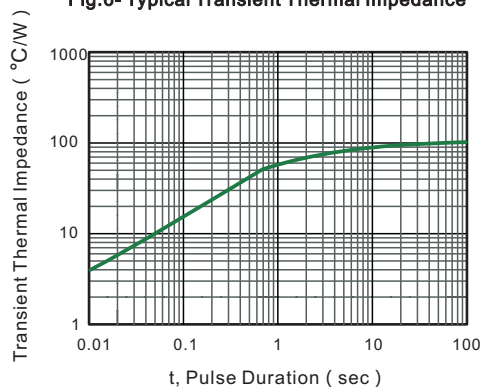
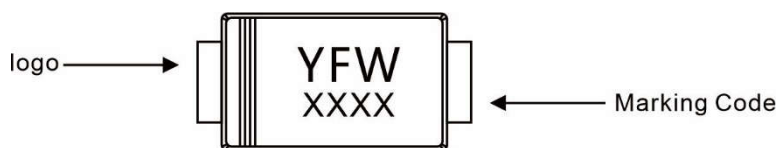


Fig.6- Typical Transient Thermal Impedance



Marking Diagram



Ordering information

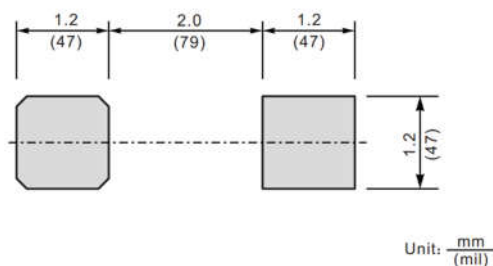
Package	Packing Description	Packing Quantity
SOD-123FL	Tape/Reel, 7" reel	3000PCS/Reel 120000PCS/Cartron

Package Dimensions

SOD-123FL

Dim.	Millimeter(mm)		mil	
	Min.	Max.	Min.	Max.
A	0.9	1.3	35	43
C	0.12	0.20	4.7	7.9
D	2.6	2.9	102	114
E	1.7	1.9	67	75
e	0.8	1.1	31	43
g	0.7	0.9	28	35
HE	3.5	3.8	138	150
∠	7°			

The recommended mounting pad size



Disclaimer

The information presented in this document is for reference only. Guangdong Youfeng Microelectronics Co.,Ltd. reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise. The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), YFW or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale. This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <https://www.yfwdiode.com>, or consult YFW sales office for further assistance.